



T-29-23

MPS2924/FTSO2924

NPN Small Signal General
Purpose Amplifier

- V_{CE0} 25 V (Min)
- h_{FE} ... 150-300 @ 2.0 mA

PACKAGE	
MPS2924	TO-92
FTSO2924	TO-236AA/AB

ABSOLUTE MAXIMUM RATINGS (Note 1)**Temperatures**

Storage Temperature	-55° C to 150° C
Operating Junction Temperature	150° C

Power Dissipation (Notes 2 & 3)

Total Dissipation at	MPS	FTSO
25° C Ambient Temperature	0.625 W	0.350 W*
70° C Ambient Temperature	0.400 W	
25° C Case Temperature	1.0 W	

Voltages & Currents

V_{CE0} Collector to Emitter Voltage	25 V
(Note 4)	
V_{CBO} Collector to Base Voltage	25 V
V_{EBO} Emitter to Base Voltage	5.0 V
I_C Collector Current	100 mA

ELECTRICAL CHARACTERISTICS (25° C Ambient Temperature unless otherwise noted) (Note 5)

SYMBOL	CHARACTERISTIC	MIN	MAX	UNITS	TEST CONDITIONS
I_{CBO}	Collector Cutoff Current		500 15	nA μ A	$V_{CB} = 25$ V, $I_E = 0$ $V_{CB} = 25$ V, $I_E = 0$, $T_A = 100^\circ$
I_{EBO}	Emitter Cutoff Current		500	nA	$V_{EB} = 5.0$ V, $I_C = 0$
h_{fe}	Small Signal Current Gain	150	300		$V_{CE} = 10$ V, $I_C = 2.0$ mA, $f = 1.0$ kHz
C_{ob}	Output Capacitance		12	pF	$V_{CB} = 10$ V, $I_E = 0$, $f = 1.0$ MHz

NOTES:

1. These ratings are limiting values above which the serviceability of any individual semiconductor device may be impaired.
 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
 3. These ratings give a maximum junction temperature of 150° C and (TO-92) junction-to-case thermal resistance of 125° C/W (derating factor of 8.0 mW/° C); junction-to-ambient thermal resistance of 200° C/W (derating factor of 5.0 mW/° C); (TO-236) junction-to-ambient thermal resistance of 357° C/W (derating factor of 2.8 mW/° C).
 4. Rating refers to a high current point where collector to emitter voltage is lowest.
 5. For product family characteristic curves, refer to Curve Set T144.
- * Package mounted on 99.5% alumina 8 mm x 8 mm x 0.6 mm.